

# **Small Outline Optoisolators** Transistor Output (Low Input Current)

These devices consist of a gallium arsenide infrared emitting diode optically coupled to a monolithic silicon phototransistor detector, in a surface mountable, small outline, plastic package. They are ideally suited for high density applications, and eliminate the need for through–the–board mounting.

- • Convenient Plastic SOIC-8 Surface Mountable Package Style
- • Low LED Input Current Required, for Easier Logic Interfacing
- • Standard SOIC-8 Footprint, with 0.050" Lead Spacing
- · Compatible with Dual Wave, Vapor Phase and IR Reflow Soldering
- • High Input–Output Isolation of 3000 Vac (rms) Guaranteed
- • UL Recognized **W** File #E90700, Volume 2

#### **Ordering Information:**

- •To obtain MOC215, 216, 217 in Tape and Reel, add R2 suffix to device numbers: R2 = 2500 units on 13" reel
- •To obtain MOC215, 216, 217 in quantities of 50 (shipped in sleeves) No Suffix

#### Marking Information:

- MOC215 = 215
- MOC216 = 216
- MOC217 = 217

#### Applications:

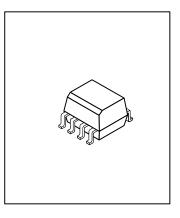
- • Low power Logic Circuits
- · Interfacing and coupling systems of different potentials and impedances
- •Telecommunications equipment
- Portable electronics

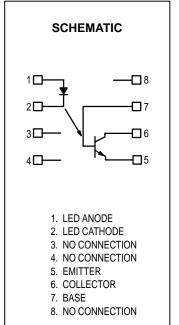
MAXIMUM RATINGS (T<sub>A</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
INPUT LED			
Forward Current — Continuous	١ <sub>F</sub>	60	mA
Forward Current — Peak (PW = 100 µs, 120 pps)	l <sub>F</sub> (pk)	1.0	А
Reverse Voltage	VR	6.0	V
LED Power Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	PD	90 0.8	mW mW/°C
OUTPUT TRANSISTOR			
Collector–Emitter Voltage	VCEO	30	V
Collector-Base Voltage	VCBO	70	V
Emitter–Collector Voltage	V <sub>ECO</sub>	7.0	V
Collector Current — Continuous	ΙC	150	mA
Detector Power Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	PD	150 1.76	mW mW/°C

# MOC215 MOC216 MOC217

# SMALL OUTLINE OPTOISOLATORS TRANSISTOR OUTPUT







#### MAXIMUM RATINGS — continued (T<sub>A</sub> = 25°C unless otherwise noted)

Rating			Va	lue	Unit
TOTAL DEVICE					
Input–Output Isolation Voltage(1,2) (60 Hz, 1.0 sec. duration)			30	00	Vac(rms)
Total Device Power Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C		PD		50 94	mW mW/°C
Ambient Operating Temperature Range <sup>(3)</sup>		ТА	-45 to	o +100	°C
Storage Temperature Range <sup>(3)</sup>		T <sub>stg</sub>	-45 to	+125	°C
Lead Soldering Temperature (1/16" from case, 10 sec. duration)		—	20	60	°C
ELECTRICAL CHARACTERISTICS (T <sub>A</sub> = 25°C unless otherw	vise noted) <sup>(4)</sup>		-		
Characteristic	Symbol	Min	<b>Typ</b> (4)	Max	Unit
INPUT LED	ł				
Forward Voltage (I <sub>F</sub> = 1.0 mA)	VF	_	1.05	1.3	V
Reverse Leakage Current (V <sub>R</sub> = 6.0 V)	IR	_	0.1	100	μA
Capacitance	С	_	18	_	pF
OUTPUT TRANSISTOR					
Collector–Emitter Dark Current $(V_{CE} = 5.0 \text{ V}, T_A = 25^{\circ}\text{C})$	I <sub>CEO</sub> 1	_	1.0	50	nA
(V <sub>CE</sub> = 5.0 V, T <sub>A</sub> = 100°C)	I <sub>CEO</sub> 2	_	1.0	_	μA
Collector–Emitter Breakdown Voltage ( $I_C = 100 \ \mu A$ )	V(BR)CEO	30	90	_	V
Emitter–Collector Breakdown Voltage (I <sub>E</sub> = 100 $\mu$ A)	V(BR)ECO	7.0	7.8	—	V
Collector–Emitter Capacitance (f = 1.0 MHz, $V_{CE} = 0$ )	CCE	—	7.0	—	pF
COUPLED					
Output Collector Current         MOC215           (IF = 1.0 mA, V <sub>CE</sub> = 5.0 V)         MOC216           MOC217         MOC217		200 (20) 500 (50) 1.0 (100)	500(50) 800 (80) 1.3 (130)		μΑ (%) μΑ (%) mA (%)
Collector–Emitter Saturation Voltage (I <sub>C</sub> = 100 $\mu$ A, I <sub>F</sub> = 1.0 mA)	V <sub>CE(sat)</sub>	—	0.35	0.4	V
Turn–On Time (I <sub>C</sub> = 2.0 mA, V <sub>CC</sub> = 10 V, R <sub>L</sub> = 100 $\Omega$ )	ton	_	7.5	_	μs
Turn–Off Time (I <sub>C</sub> = 2.0 mA, V <sub>CC</sub> = 10 V, R <sub>L</sub> = 100 $\Omega$ )	toff	_	5.7	_	μs
Rise Time (I <sub>C</sub> = 2.0 mA, V <sub>CC</sub> = 10 V, R <sub>L</sub> = 100 $\Omega$ )	tr	_	3.2	_	μs
Fall Time (I <sub>C</sub> = 2.0 mA, V <sub>CC</sub> = 10 V, R <sub>L</sub> = 100 $\Omega$ )	tf	—	4.7	_	μs
Input–Output Isolation Voltage (f = 60 Hz, t = 1.0 sec.) <sup>(1,2)</sup>	VISO	3000	_		Vac(rms)
Isolation Resistance $(V_{I-O} = 500 V)^{(2)}$	R <sub>ISO</sub>	10 <sup>11</sup>	—	_	Ω
Isolation Capacitance ( $V_{I-O} = 0$ , f = 1.0 MHz) <sup>(2)</sup>	CISO	_	0.2	_	pF

1. Input–Output Isolation Voltage,  $V_{ISO}$ , is an internal device dielectric breakdown rating.

2. For this test, pins 1 and 2 are common, and pins 5, 6 and 7 are common.

3. Refer to Quality and Reliability Section in Opto Data Book for information on test conditions.

4. Always design to the specified minimum/maximum electrical limits (where applicable).

5. Current Transfer Ratio (CTR) =  $I_C/I_F \times 100\%$ .



#### **TYPICAL CHARACTERISTICS**

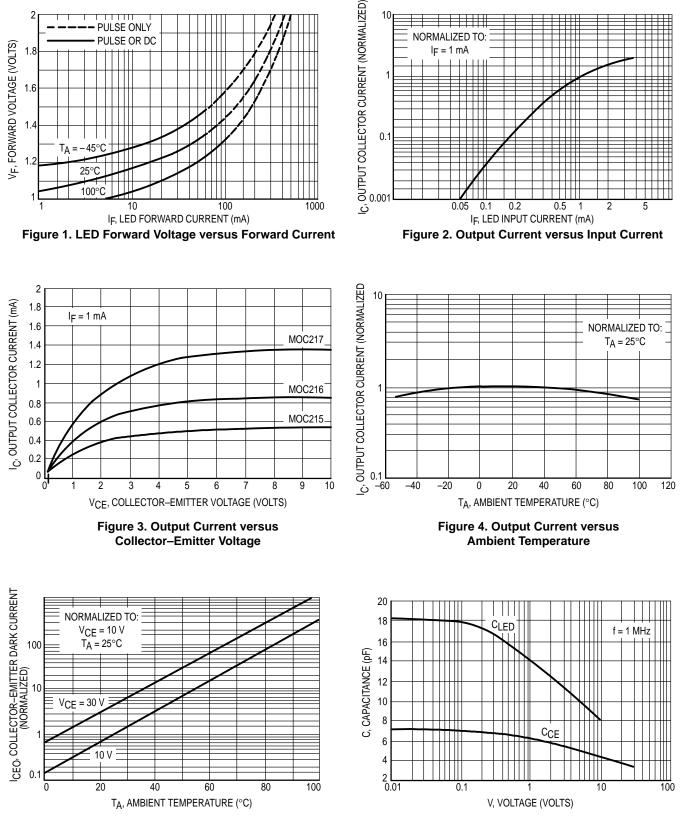


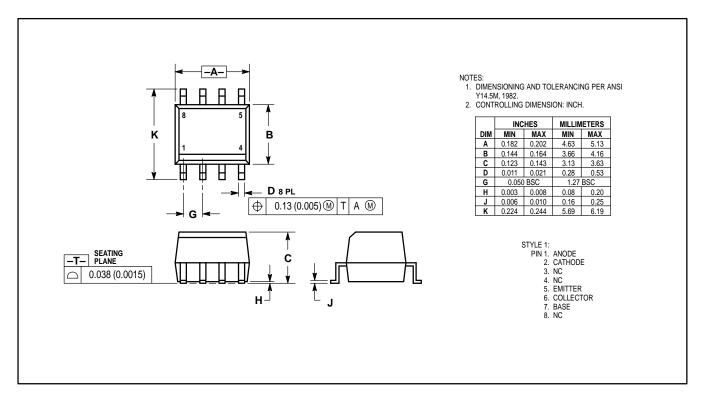
Figure 5. Dark Current versus Ambient Temperature





# MOC215, MOC216, MOC217

#### PACKAGE DIMENSIONS





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- 2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

	WOC215-W - 506 Filototransistor Coupler		
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Applications

- Low power logic circuits
- Interfacing and coupling systems of different potentials and impedancesTelecommunications equipment
- Portable electronics

# Ordering information

The following options can be ordered with this part:

Option	Order Entry Identifier	Description
R1	R1	Surface-Mount Lead Bend Tape and Reel (500-pc reel)
R2	R2	Surface-Mount Lead Bend Tape and Reel (2500-pc reel)

#### back to top

Product status/pricing/packaging

Product	Product status	Pricing*	Package type	Leads	Packing method
MOC215-M	Full Production	\$0.264	SOIC	8	RAIL
MOC215R1-M	Full Production	\$0.273	SOIC	8	TAPE REEL
MOC215R2-M	Full Production	\$0.273	SOIC	8	TAPE REEL

\* 1,000 piece Budgetary Pricing

# back to top

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#### back to top

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Product	Product status	Pricing*	Package type	Leads	Packing method
MOC216-M	Full Production	\$0.281	SOIC	8	RAIL
MOC216R1-M	Full Production	\$0.291	SOIC	8	TAPE REEL
MOC216R2-M	Full Production	\$0.291	SOIC	8	TAPE REEL

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# back to top

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back to top

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# back to top

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Datasheets for products beginning with CNY

<u>CNY17-1-M</u>	<u>CNY17-2-M</u>	<u>CNY17-3-M</u>

back to top

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 H11AA1-M replaced by H11AA1	H11AA2-M replaced by H11AA2

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H11AA3-M replaced by H11AA3	H11AA4-M replaced by H11AA4	H11AV1-M
H11AV1A-M	<u>H11AV2-M</u>	H11AV2A-M
H11B1 <mark>-M</mark> replaced by <u>H11B1</u>	H11B3-M replaced by H11B3	H11D1-M replaced by H11D1
H11D2-M replaced by <u>H11D2</u>	H11G1- <mark>M</mark> replaced by <u>H11G1</u>	H11G2-M replaced by H11G2
H11G3- <mark>M</mark> replaced by <u>H11G3</u>	<u>H11L1-M</u>	H11L2-M
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back to top

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back to top

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<u>MOC205-M</u>	MOC206-M	<u>MOC207-M</u>
<u>MOC208-M</u>	<u>MOC211-M</u>	<u>MOC212-M</u>
<u>MOC213-M</u>	<u>MOC215-M</u>	MOC216-M
<u>MOC217-M</u>	<u>MOC223-M</u>	MOC256-M
<u>MOC3010-M</u>	<u>MOC3011-M</u>	MOC3012-M
<u>MOC3020-M</u>	<u>MOC3021-M</u>	MOC3022-M
<u>MOC3023-M</u>	<u>MOC3031-M</u>	MOC3032-M
<u>MOC3033-M</u>	<u>MOC3041-M</u>	MOC3042-M
<u>MOC3043-M</u>	<u>MOC3051-M</u>	MOC3052-M
<u>MOC3061-M</u>	<u>MOC3062-M</u>	<u>MOC3063-M</u>
<u>MOC3081-M</u>	<u>MOC3081-M</u>	<u>MOC3083-M</u>
<u>MOC3162-M</u>	MOC3163-M	<u>MOC5007-M</u>
<u>MOC5008-M</u>	<u>MOC5009-M</u>	MOC8030-M replaced by MOC8030

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MOC8050-M replaced by MOC8050	MOC8080-M replaced by MOC8080	MOC8100-M
MOC8204-M replaced by MOC8204	MOCD207-M	MOCD208-M
MOCD211-M MOCD223-M	MOCD213-M	MOCD217-M

back to top

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